

LT1014, LT1014A, LT1014D QUAD PRECISION OPERATIONAL AMPLIFIERS

SLOS039C – JULY 1989 – REVISED SEPTEMBER 1999

- **Single-Supply Operation:**
Input Voltage Range Extends to Ground,
and Output Swings to Ground While
Sinking Current
- **Input Offset Voltage 300 μV Max at 25°C for
LT1014**
- **Offset Voltage Temperature Coefficient
2.5 $\mu\text{V}/^\circ\text{C}$ Max for LT1014**
- **Input Offset Current 1.5 nA Max at 25°C for
LT1014**
- **High Gain 1.2 $\text{V}/\mu\text{V}$ Min ($R_L = 2 \text{ k}\Omega$), 0.5 $\text{V}/\mu\text{V}$
Min ($R_L = 600 \Omega$) for LT1014**
- **Low Supply Current 2.2 mA Max at 25°C for
LT 1014**
- **Low Peak-to-Peak Noise Voltage
0.55 μV Typ**
- **Low Current Noise 0.07 $\text{pA}/\sqrt{\text{Hz}}$ Typ**

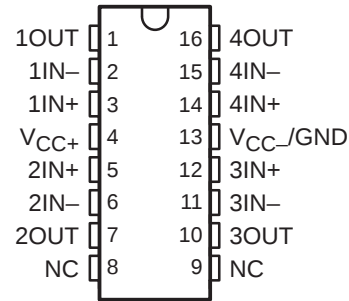
description

The LT1014, LT1014A, and LT1014D are quad precision operational amplifiers with 14-pin industry-standard configuration. They feature low offset-voltage temperature coefficient, high gain, low supply current, and low noise.

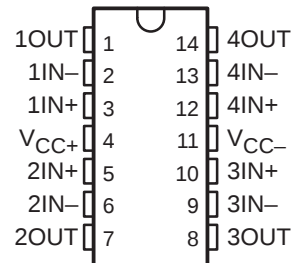
The LT1014, LT1014A, and LT1014D can be operated with both dual $\pm 15\text{-V}$ and single 5-V power supplies. The common-mode input voltage range includes ground, and the output voltage can also swing to within a few millivolts of ground. Crossover distortion is eliminated.

The LT1014C and LT1014 AC are characterized for operation from 0°C to 70°C. The LT1014I and LT1014DI are characterized for operation from -40°C to 105°C. The LT1014M, LT1014AM and LT1014DM are characterized for operation over the full military temperature range of -55°C to 125°C.

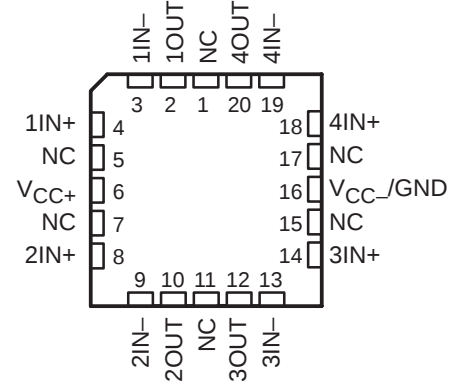
**DW PACKAGE
(TOP VIEW)**



**J OR N PACKAGE
(TOP VIEW)**



**FK PACKAGE
(TOP VIEW)**



NC – No internal connection



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

**TEXAS
INSTRUMENTS**

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LT1014, LT1014A, LT1014D

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AVAILABLE OPTIONS

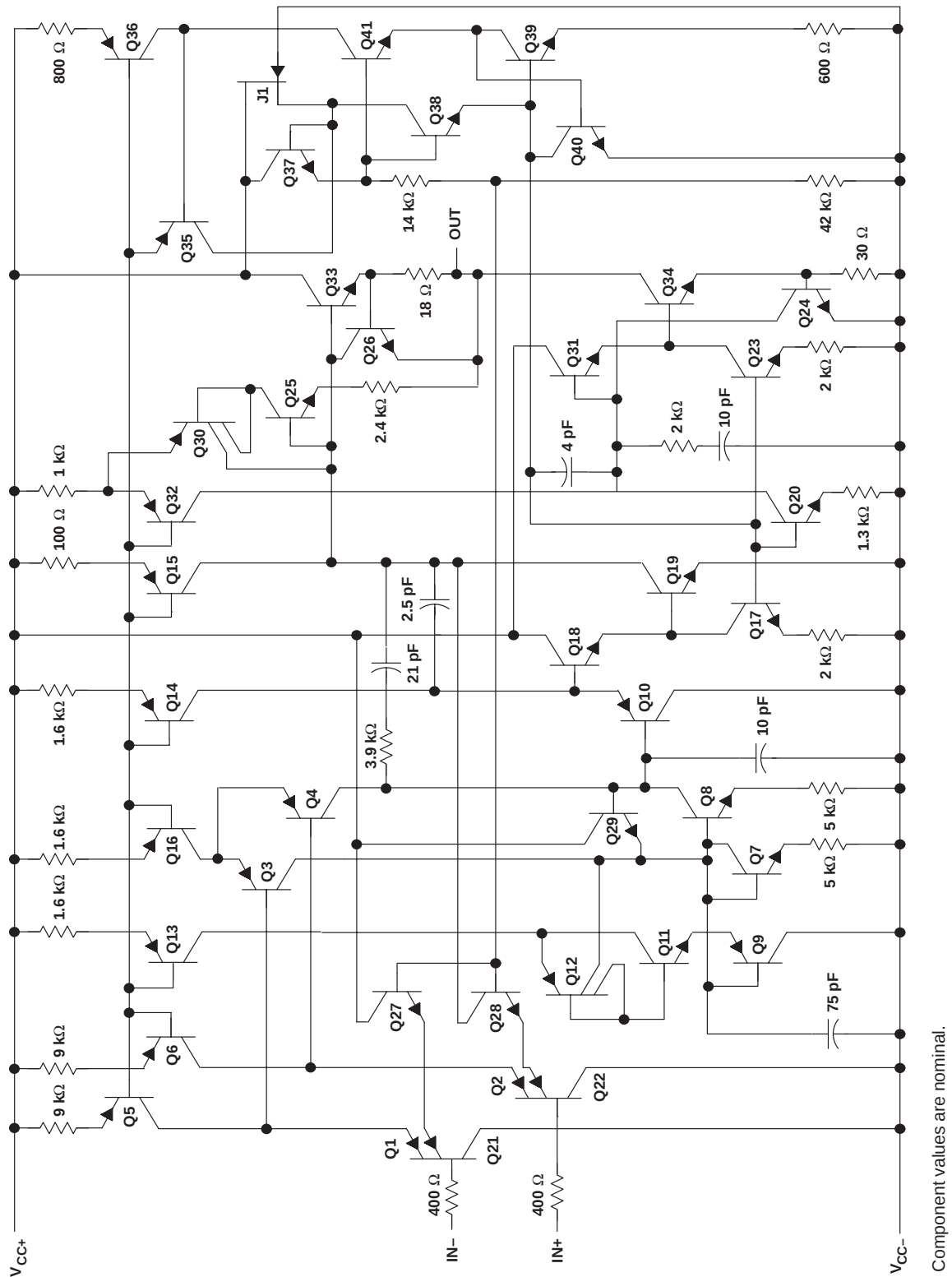
T _A	V _{IO} max AT 25°C	PACKAGED DEVICES			
		SMALL OUTLINE (DW)	CHIP CARRIER (FK)	CERAMIC DIP (J)	PLASTIC DIP (N)
0°C to 70°C	300 µV 800 µV	— LT1014DDW	— —	— —	LT1014CN LT1014DN
–40°C to 105°C	300 µV 800 µV	— LT1014DIDW	— —	— —	LT1014IN LT1014DIN
–55°C to 125°C	180 µV 300 µV 800 µV	— — LT1014DMDW	LT1014AMFK LT1014MFK —	LT1014AMJ LT1014MJ —	— LT1014MN LT1014DMN

The DW package is available taped and reeled. Add the suffix R to the device type (e.g., LT1014DDWR).



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schematic (each amplifier)



LT1014, LT1014A, LT1014D

QUAD PRECISION OPERATIONAL AMPLIFIERS

SLOS039C – JULY 1989 – REVISED SEPTEMBER 1999

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage (see Note 1): V_{CC+}	22 V
V_{CC-}	–22 V
Differential input voltage (see Note 2)	±30 V
Input voltage range, V_I (any input) (see Note 1)	$V_{CC-} - 5 \text{ V}$ to V_{CC+}
Duration of short-circuit current at (or below) $T_A = 25^\circ\text{C}$ (see Note 3)	Unlimited
Continuous total power dissipation	See Dissipation Rating Table
Operating free-air temperature range, T_A : LT1014C, LT1014DC	–0°C to 70°C
LT1014I, LT1014DI	–40°C to 105°C
LT1014M, LT1014AM, LT1014DM	–55°C to 125°C
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds: J package	300°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds: DW or N package	260°C
Case temperature for 60 seconds: FK package	260°C
Storage temperature range, T_{stg}	–65°C to 150°C

[†] Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES:
1. All voltage values, except differential voltages, are with respect to the midpoint between V_{CC+} and V_{CC-} .
 2. Differential voltages are at the noninverting input with respect to the inverting input.
 3. The output may be shorted to either supply.

DISSIPATION RATING TABLE

PACKAGE	$T_A \leq 25^\circ\text{C}$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25^\circ\text{C}$	$T_A = 70^\circ\text{C}$ POWER RATING	$T_A = 105^\circ\text{C}$ POWER RATING	$T_A = 125^\circ\text{C}$ POWER RATING
DW	1025 mW	8.2 mW/°C	656 mW	369 mW	205 mW
FK	1375 mW	11.0 mW/°C	880 mW	495 mW	275 mW
J	1375 mW	11.0 mW/°C	880 mW	495 mW	275 mW
N	1150 mW	9.2 mW/°C	736 mW	414 mW	230 mW



LT1014, LT1014A, LT1014D

QUAD PRECISION OPERATIONAL AMPLIFIERS

SLOS039C – JULY 1989 – REVISED SEPTEMBER 1999

electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15\text{ V}$, $V_{IC} = 0$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	LT1014C			LT1014DC			UNIT
			MIN	TYP [‡]	MAX	MIN	TYP [‡]	MAX	
V_{IO} Input offset voltage	$R_S = 50\ \Omega$	25°C	60	300		200	800		μV
		Full range			550			1000	
$\alpha_{V_{IO}}$ Temperature coefficient of input offset voltage		Full range	0.4	2.5		0.7	5		$\mu\text{V}/^\circ\text{C}$
Long-term drift of input offset voltage		25°C	0.5			0.5			$\mu\text{V}/\text{mo}$
I_{IO} Input offset current		25°C	0.15	1.5		0.15	1.5		nA
		Full range			2.8			2.8	
I_{IB} Input bias current		25°C	–12	–30		–12	–30		nA
		Full range			–38			–38	
V_{ICR} Common-mode input voltage range		25°C	–15 to 13.5	–15.3 to 13.8		–15 to 13.5	–15.3 to 13.8		V
		Full range	–15 to 13			–15 to 13			
V_{OM} Maximum peak output voltage swing	$R_L = 2\ \text{k}\Omega$	25°C	± 12.5	± 14		± 12.5	± 14		V
		Full range	± 12			± 12			
AVD Large-signal differential voltage amplification	$V_O = \pm 10\text{ V}$, $R_L = 600\ \Omega$	25°C	0.5	2		0.5	2		$\text{V}/\mu\text{V}$
	$V_O = \pm 10\text{ V}$, $R_L = 2\ \text{k}\Omega$	25°C	1.2	8		1.2	8		
		Full range	0.7			0.7			
$CMRR$ Common-mode rejection ratio	$V_{IC} = -15\text{ V to } 13.5\text{ V}$	25°C	97	117		97	117		dB
	$V_{IC} = -15\text{ V to } 13\text{ V}$	Full range	94			94			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 2\text{ V to } \pm 18\text{ V}$	25°C	100	117		100	117		dB
		Full range	97			97			
Channel separation	$V_O = \pm 10\text{ V}$, $R_L = 2\ \text{k}\Omega$	25°C	120	137		120	137		dB
r_{id} Differential input resistance		25°C	70	300		70	300		$\text{M}\Omega$
r_{ic} Common-mode input resistance		25°C	4			4			$\text{G}\Omega$
I_{CC} Supply current per amplifier		25°C	0.35	0.55		0.35	0.55		mA
		Full range			0.6			0.6	

[†] Full range is 0°C to 70°C.

[‡] All typical values are at $T_A = 25^\circ\text{C}$.



LT1014, LT1014A, LT1014D

QUAD PRECISION OPERATIONAL AMPLIFIERS

SLOS039C – JULY 1989 – REVISED SEPTEMBER 1999

electrical characteristics at specified free-air temperature, $V_{CC\pm} = 5\text{ V}$, $V_{CC-} = 0$, $V_O = 1.4\text{ V}$, $V_{IC} = 0$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	LT1014C			LT1014DC			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$R_S = 50\ \Omega$	25°C		90	450		250	950	μV
		Full range			570			1200	
I_{IO} Input offset current		25°C		0.2	2		0.2	2	nA
		Full range			6			6	
I_{IB} Input bias current		25°C		-15	-50		-15	-50	nA
		Full range			-90			-90	
V_{ICR} Common-mode input voltage range		25°C	0 to 3.5	-0.3 to 3.8		0 to 3.5	-0.3 to 3.8		V
		Full range	0 to 3			0 to 3			
V_{OM} Maximum peak output voltage swing	Output low, No load	25°C		15	25		15	25	mV
	Output low, $R_L = 600\ \Omega$ to GND	25°C		5	10		5	10	
		Full range			13			13	
	Output low, $I_{\text{sink}} = 1\text{ mA}$	25°C		220	350		220	350	V
	Output high, No load	25°C		4	4.4		4	4.4	
	Output high, $R_L = 600\ \Omega$ to GND	25°C		3.4	4		3.4	4	
		Full range		3.2			3.2		
A_{VD} Large-signal differential voltage amplification	$V_O = 5\text{ mV}$ to 4 V , $R_L = 500\ \Omega$	25°C		1			1		V/ μV
I_{CC} Supply current per amplifier		25°C		0.3	0.5		0.3	0.5	mA
		Full range			0.55			0.55	

† Full range is 0°C to 70°C.

operating characteristics, $V_{CC\pm} = \pm 15\text{ V}$, $V_{IC} = 0$, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
SR	Slew rate		0.2	0.4		V/ μs
V_n	Equivalent input noise voltage	$f = 10\text{ Hz}$		24		$\text{nV}/\sqrt{\text{Hz}}$
		$f = 1\text{ kHz}$		22		
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ Hz}$ to 10 Hz		0.55		μV
I_n	Equivalent input noise current	$f = 10\text{ Hz}$		0.07		$\text{pA}/\sqrt{\text{Hz}}$



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LT1014, LT1014A, LT1014D QUAD PRECISION OPERATIONAL AMPLIFIERS

SLOS039C – JULY 1989 – REVISED SEPTEMBER 1999

electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15\text{ V}$, $V_{IC} = 0$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	LT1014I			LT1014DI			UNIT
			MIN	TYP ‡	MAX	MIN	TYP ‡	MAX	
V_{IO} Input offset voltage	$R_S = 50\ \Omega$	25°C	60	300		200	800		μV
		Full range			550			1000	
$\alpha_{V_{IO}}$ Temperature coefficient of input offset voltage		Full range	0.4	2.5		0.7	5		$\mu\text{V}/^\circ\text{C}$
Long-term drift of input offset voltage		25°C	0.5			0.5			$\mu\text{V}/\text{mo}$
I_{IO} Input offset current		25°C	0.15	1.5		0.15	1.5		nA
		Full range			2.8			2.8	
I_{IB} Input bias current		25°C	-12	-30		-12	-30		nA
		Full range			-38			-38	
V_{ICR} Common-mode input voltage range		25°C	-15 to 13.5	-15.3 to 13.8		-15 to 13.5	-15.3 to 13.8		V
		Full range			-15 to 13			-15 to 13	
V_{OM} Maximum peak output voltage swing	$R_L = 2\ \text{k}\Omega$	25°C	± 12.5	± 14		± 12.5	± 14		V
		Full range			± 12			± 12	
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 10\text{ V}$, $R_L = 600\ \Omega$	25°C	0.5	2		0.5	2		V/ μV
	$V_O = \pm 10\text{ V}$, $R_L = 2\ \text{k}\Omega$	25°C	1.2	8		1.2	8		
		Full range			0.7			0.7	
CMRR Common-mode rejection ratio	$V_{IC} = -15\text{ V to } 13.5\text{ V}$	25°C	97	117		97	117		dB
		Full range			94			94	
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 2\text{ V to } \pm 18\text{ V}$	25°C	100	117		100	117		dB
		Full range			97			97	
Channel separation	$V_O = \pm 10\text{ V}$, $R_L = 2\ \text{k}\Omega$	25°C	120	137		120	137		dB
r_{id} Differential input resistance		25°C	70	300		70	300		M Ω
r_{ic} Common-mode input resistance		25°C		4			4		G Ω
I_{CC} Supply current per amplifier		25°C	0.35	0.55		0.35	0.55		mA
		Full range			0.6			0.6	

† Full range is -40°C to 105°C .

‡ All typical values are at $T_A = 25^\circ\text{C}$.



LT1014, LT1014A, LT1014D

QUAD PRECISION OPERATIONAL AMPLIFIERS

SLOS039C – JULY 1989 – REVISED SEPTEMBER 1999

electrical characteristics at specified free-air temperature, $V_{CC+} = 5\text{ V}$, $V_{CC-} = 0$, $V_O = 1.4\text{ V}$, $V_{IC} = 0$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	LT1014I			LT1014DI			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$R_S = 50\ \Omega$	25°C	90	450		250	950		μV
		Full range		570			1200		
I_{IO} Input offset current		25°C	0.2	2		0.2	2		nA
		Full range		6			6		
I_{IB} Input bias current		25°C	-15	-50		-15	-50		nA
		Full range		-90			-90		
V_{ICR} Common-mode input voltage range		25°C	0 to 3.5	-0.3 to 3.8		0 to 3.5	-0.3 to 3.8		V
		Full range	0 to 3			0 to 3			
V_{OM} Maximum peak output voltage swing	Output low, No load	25°C	15	25		15	25		mV
	Output low, $R_L = 600\ \Omega$ to GND	25°C	5	10		5	10		
		Full range		13			13		
	Output low, $I_{\text{sink}} = 1\text{ mA}$	25°C	220	350		220	350		V
	Output high, No load	25°C	4	4.4		4	4.4		
	Output high, $R_L = 600\ \Omega$ to GND	25°C	3.4	4		3.4	4		
		Full range	3.2			3.2			
A_{VD} Large-signal differential voltage amplification	$V_O = 5\text{ mV}$ to 4 V , $R_L = 500\ \Omega$	25°C	1			1			V/ μV
I_{CC} Supply current per amplifier		25°C	0.3	0.5		0.3	0.5		mA
		Full range		0.55			0.55		

† Full range is -40°C to 105°C.

operating characteristics, $V_{CC+} = \pm 15\text{ V}$, $V_{IC} = 0$, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
SR	Slew rate		0.2	0.4		V/ μs
V_N	Equivalent input noise voltage	f = 10 Hz		24		nV/ $\sqrt{\text{Hz}}$
		f = 1 kHz		22		
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	f = 0.1 Hz to 10 Hz		0.55		μV
I_N	Equivalent input noise current	f = 10 Hz		0.07		pA/ $\sqrt{\text{Hz}}$



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LT1014, LT1014A, LT1014D

QUAD PRECISION OPERATIONAL AMPLIFIERS

SLOS039C – JULY 1989 – REVISED SEPTEMBER 1999

electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15\text{ V}$, $V_{IC} = 0$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	LT1014M			LT1014AM			LT1014DM			UNIT
			MIN	TYP [‡]	MAX	MIN	TYP [‡]	MAX	MIN	TYP [‡]	MAX	
V_{IO} Input offset voltage	$R_S = 50\ \Omega$	25°C	60	300		60	180		200	800		μV
		Full range			550		350			1000		
$\alpha_{V_{IO}}$ Temperature coefficient of input offset voltage		Full range	0.5	2.5		0.5	2		0.5	2.5		$\mu\text{V}/^\circ\text{C}$
Long-term drift of input offset voltage		25°C	0.5			0.5			0.5			$\mu\text{V}/\text{mo}$
I_{IO} Input offset current		25°C	0.15	1.5		0.15	0.8		0.15	1.5		nA
		Full range			5		2.8			5		
I_{IB} Input bias current		25°C	–12	–30		–12	–20		–12	–30		nA
		Full range			–45		–30			–45		
V_{ICR} Common-mode input voltage range		25°C	–15 to 13.5	–15.3 to 13.8		–15 to 13.5	–15.3 to 13.8		–15 to 13.5	–15.3 to 13.8		V
		Full range	–14.9 to 13			–14.9 to 13			–14.9 to 13			
V_{OM} Maximum peak output voltage swing	$R_L = 2\text{ k}\Omega$	25°C	± 12.5	± 14		± 13	± 14		± 12.5	± 14		V
		Full range	± 11.5			± 12			± 11.5			
AVD Large-signal differential voltage amplification	$V_O = \pm 10\text{ V}$, $R_L = 600\ \Omega$	25°C	0.5	2		0.8	2.2		0.5	2		$\text{V}/\mu\text{V}$
	$V_O = \pm 10\text{ V}$, $R_L = 2\text{ k}\Omega$	25°C	1.2	8		1.5	8		1.2	8		
		Full range	0.25			0.4			0.25			
$CMRR$ Common-mode rejection ratio	$V_{IC} = -15\text{ V}$ to 13.5 V	25°C	97	117		100	117		97	117		dB
	$V_{IC} = -14.9\text{ V}$ to 13 V	Full range	94			96			94			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 2\text{ V}$ to $\pm 18\text{ V}$	25°C	100	117		103	117		100	117		dB
		Full range	97			100			97			
Channel separation	$V_O = \pm 10\text{ V}$, $R_L = 2\text{ k}\Omega$	25°C	120	137		123	137		120	137		dB
r_{id} Differential input resistance		25°C	70	300		100	300		70	300		$\text{M}\Omega$
r_{ic} Common-mode input resistance		25°C	4			4			4			$\text{G}\Omega$
I_{CC} Supply current per amplifier		25°C	0.35	0.55		0.35	0.50		0.35	0.55		mA
		Full range			0.7		0.6			0.7		

[†] Full range is -55°C to 125°C .

[‡] All typical values are at $T_A = 25^\circ\text{C}$.



POST OFFICE BOX 655303 • DALLAS, TEXAS 75265

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SLOS039C – JULY 1989 – REVISED SEPTEMBER 1999

electrical characteristics at specified free-air temperature, $V_{CC+} = 5\text{ V}$, $V_{CC-} = 0$, $V_O = 1.4\text{ V}$, $V_{IC} = 0$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	LT1014M			LT1014AM			LT1014DM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$R_S = 50\Omega$	25°C		90	450		90	280		250	950	μV
		Full range		400	1500		400	960		800	2000	
	$R_S = 50\Omega$, $V_{IC} = 0.1\text{ V}$	125°C		200	750		200	480		560	1200	
I_{IO} Input offset current		25°C		0.2	2		0.2	1.3		0.2	2	nA
		Full range			10			7			10	
I_{IB} Input bias current		25°C		-15	-50		-15	-35		-15	-50	nA
		Full range			-120			-90			-120	
V_{ICR} Common-mode input voltage range		25°C	0 to 3.5	-0.3 to 3.8		0 to 3.5	-0.3 to 3.8		0 to 3.5	-0.3 to 3.8		V
		Full range	0.1 to 3			0.1 to 3			0.1 to 3			
V_{OM} Maximum peak output voltage swing	Output low, No load	25°C		15	25		15	25		15	25	mV
	Output low, $R_L = 600\Omega$ to GND	25°C		5	10		5	10		5	10	
		Full range			18			15			18	
	Output low, $I_{\text{sink}} = 1\text{ mA}$	25°C		220	350		220	350		220	350	V
	Output high, No load	25°C	4	4.4		4	4.4		4	4.4		
	Output high, $R_L = 600\Omega$ to GND	25°C	3.4	4		3.4	4		3.4	4		
	Full range		3.1			3.2			3.1			
A_{VD} Large-signal differential voltage amplification	$V_O = 5\text{ mV to }4\text{ V}$, $R_L = 500\Omega$	25°C		1			1			1		$\text{V}/\mu\text{V}$
I_{CC} Supply current per amplifier		25°C		0.3	0.5		0.3	0.45		0.3	0.5	mA
		Full range			0.65			0.55			0.65	

† Full range is -55°C to 125°C.

operating characteristics, $V_{CC\pm} = \pm 15\text{ V}$, $V_{IC} = 0$, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
SR	Slew rate		0.2	0.4		$\text{V}/\mu\text{s}$
V_n	Equivalent input noise voltage	$f = 10\text{ Hz}$		24		$\text{nV}/\sqrt{\text{Hz}}$
		$f = 1\text{ kHz}$		22		
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ Hz to }10\text{ Hz}$		0.55		μV
I_n	Equivalent input noise current	$f = 10\text{ Hz}$		0.07		$\text{pA}/\sqrt{\text{Hz}}$



TYPICAL CHARACTERISTICS

Table of Graphs

		FIGURE
V_{IO}	Input offset voltage vs Balanced source resistance	1
V_{IO}	Input offset voltage vs Free-air temperature	2
ΔV_{IO}	Warm-Up Change in input offset voltage vs Elapsed time	3
I_{IO}	Input offset current vs Free-air temperature	4
I_{IB}	Input bias current vs Free-air temperature	5
V_{IC}	Common-mode input voltage vs Input bias current	6
A_{VD}	Differential voltage amplification	
	vs Load resistance	7, 8
	vs Frequency	9, 10
	Channel separation vs Frequency	11
	Output saturation voltage vs Free-air temperature	12
CMRR	Common-mode rejection ratio vs Frequency	13
k_{SVR}	Supply-voltage rejection ratio vs Frequency	14
I_{CC}	Supply current vs Free-air temperature	15
I_{OS}	Short-circuit output current vs Elapsed time	16
V_n	Equivalent input noise voltage vs Frequency	17
I_n	Equivalent input noise current vs Frequency	17
$V_{N(PP)}$	Peak-to-peak input noise voltage vs Time	18
	Pulse response (small signal) vs Time	19, 21
	Pulse response (large signal) vs Time	20, 22, 23
	Phase shift vs Frequency	9

LT1014, LT1014A, LT1014D QUAD PRECISION OPERATIONAL AMPLIFIERS

SLOS039C – JULY 1989 – REVISED SEPTEMBER 1999

TYPICAL CHARACTERISTICS†

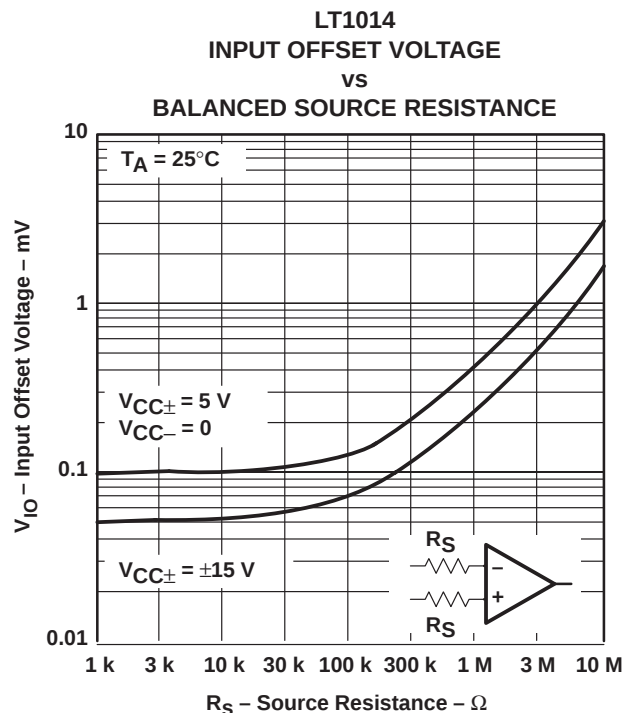


Figure 1

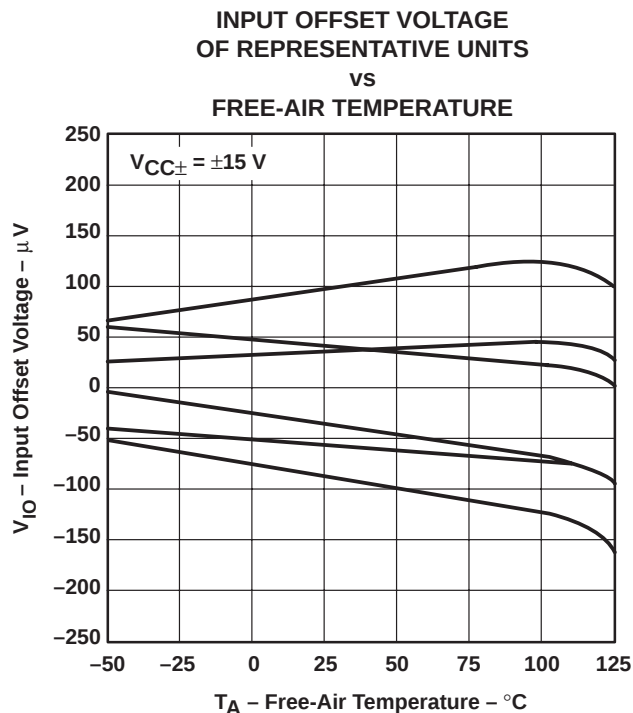


Figure 2

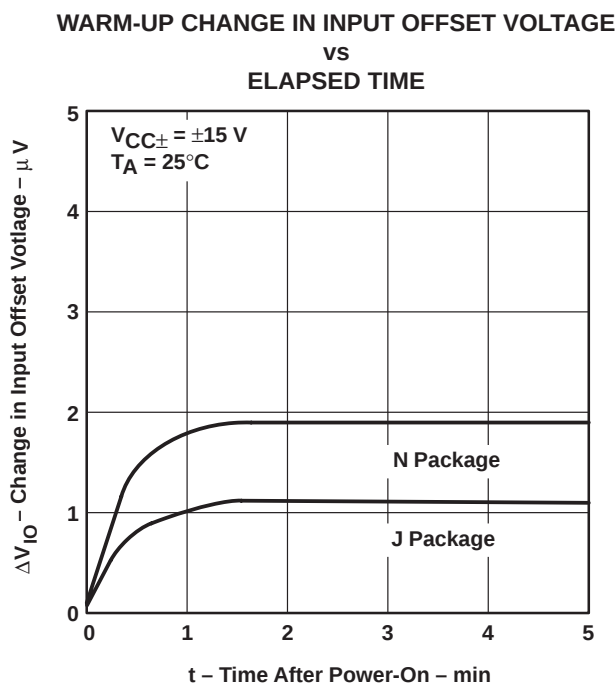


Figure 3

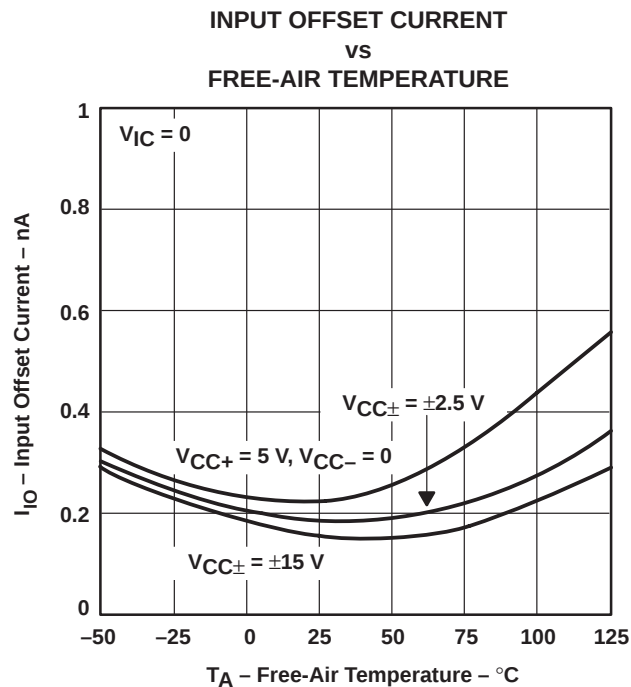


Figure 4

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS†

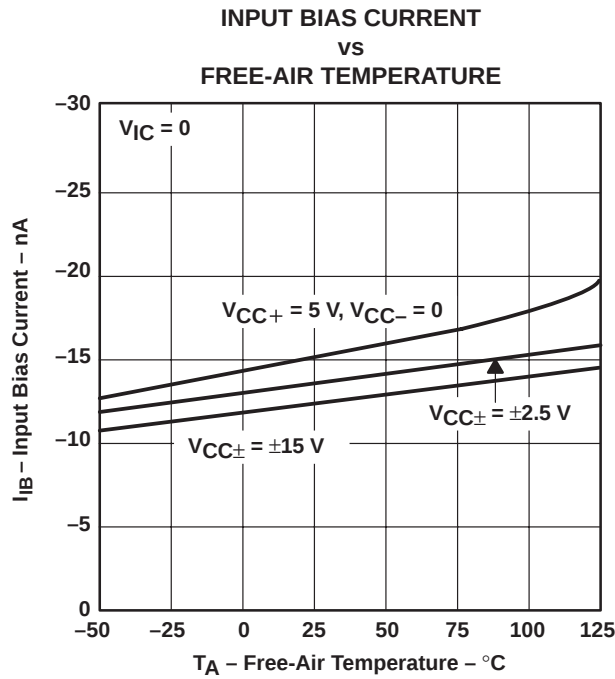


Figure 5

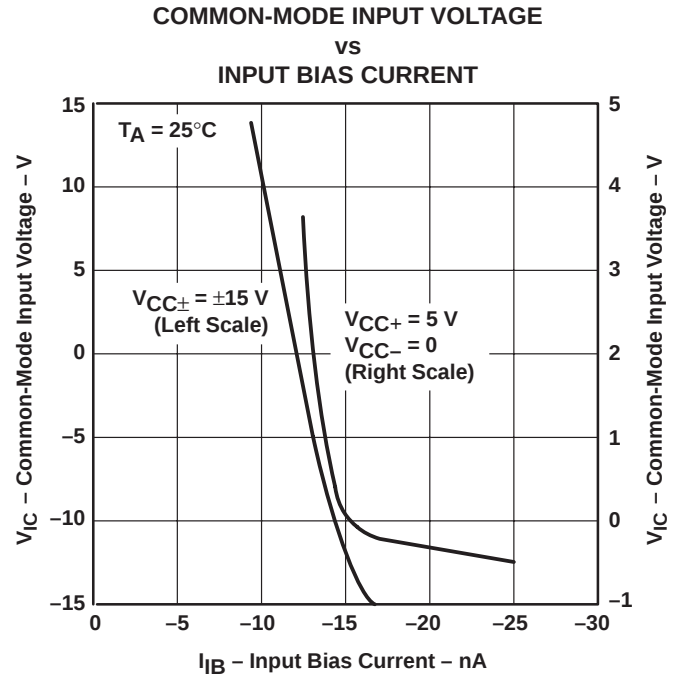


Figure 6

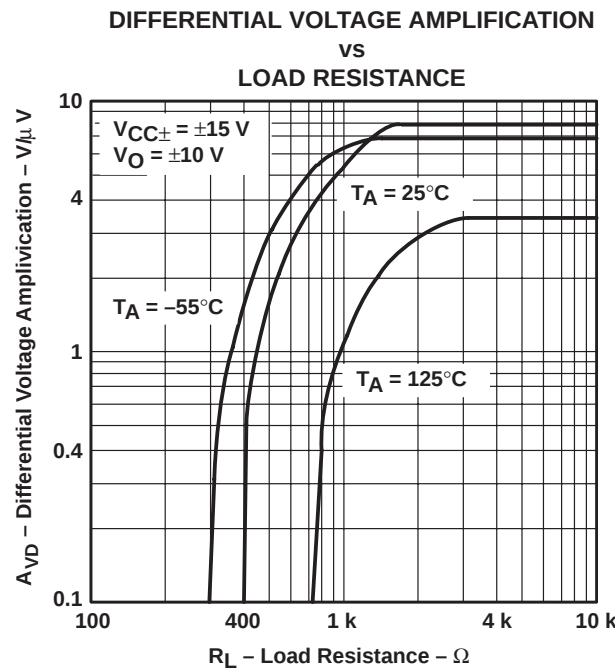


Figure 7

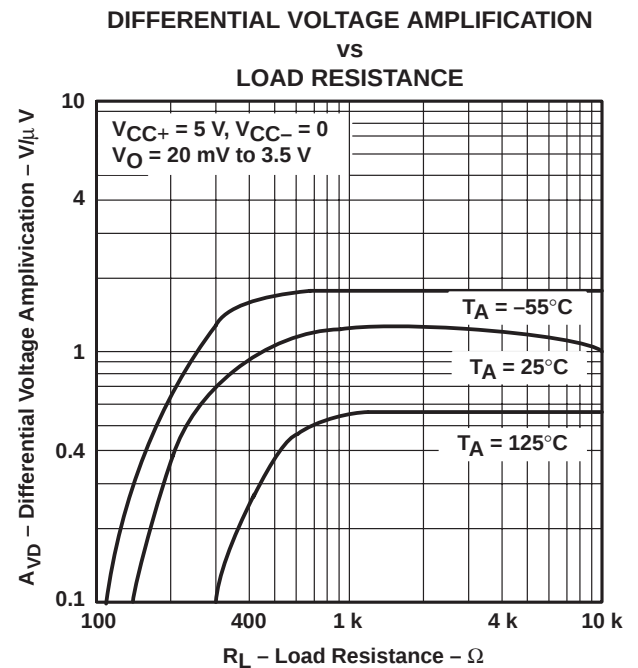


Figure 8

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

LT1014, LT1014A, LT1014D QUAD PRECISION OPERATIONAL AMPLIFIERS

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TYPICAL CHARACTERISTICS†

DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE SHIFT

VS
FREQUENCY

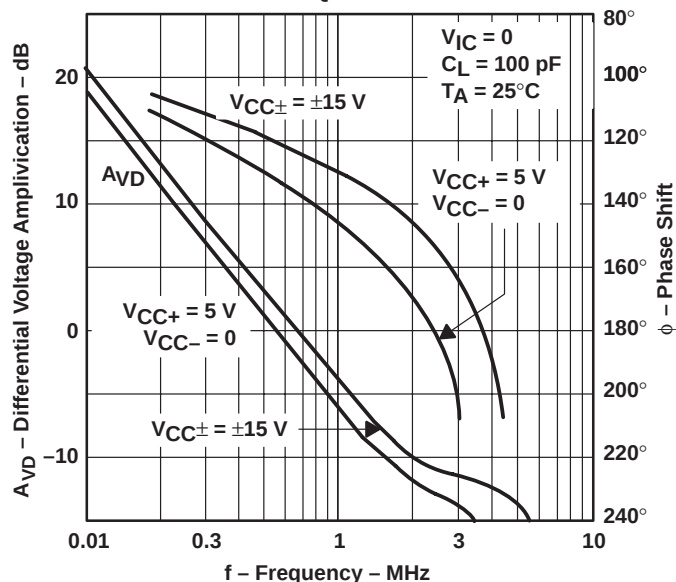


Figure 9

DIFFERENTIAL VOLTAGE AMPLIFICATION VS FREQUENCY

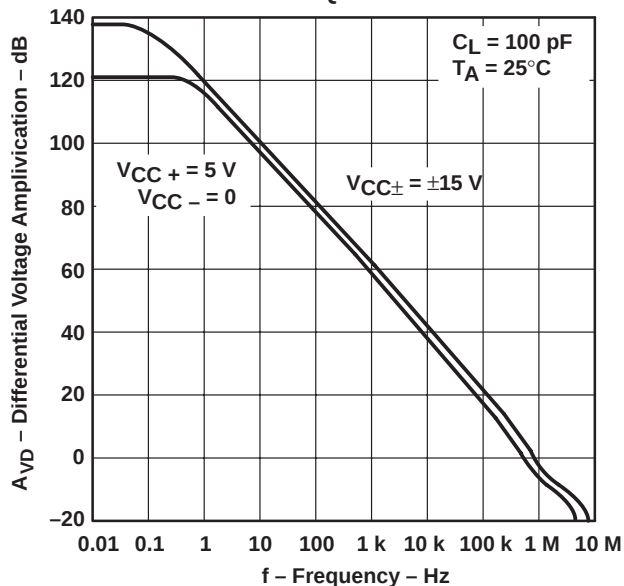


Figure 10

CHANNEL SEPARATION VS FREQUENCY

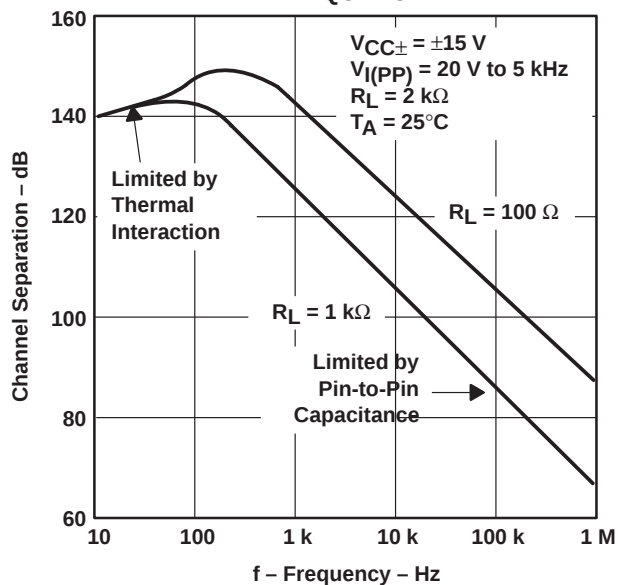


Figure 11

OUTPUT SATURATION VOLTAGE VS FREE-AIR TEMPERATURE

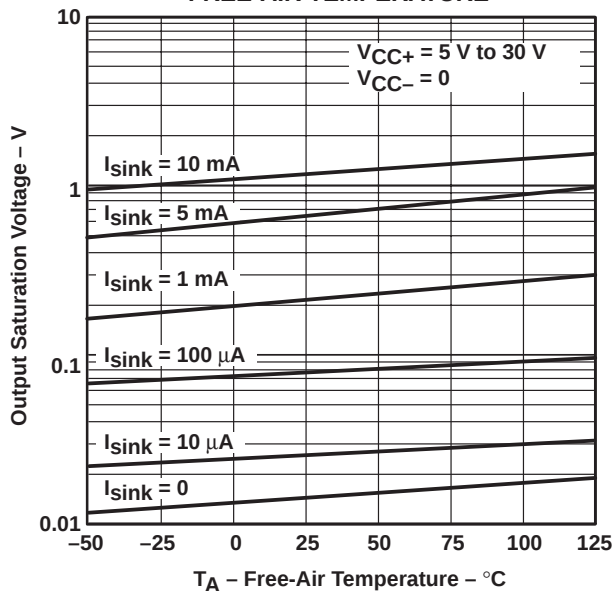


Figure 12

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS†

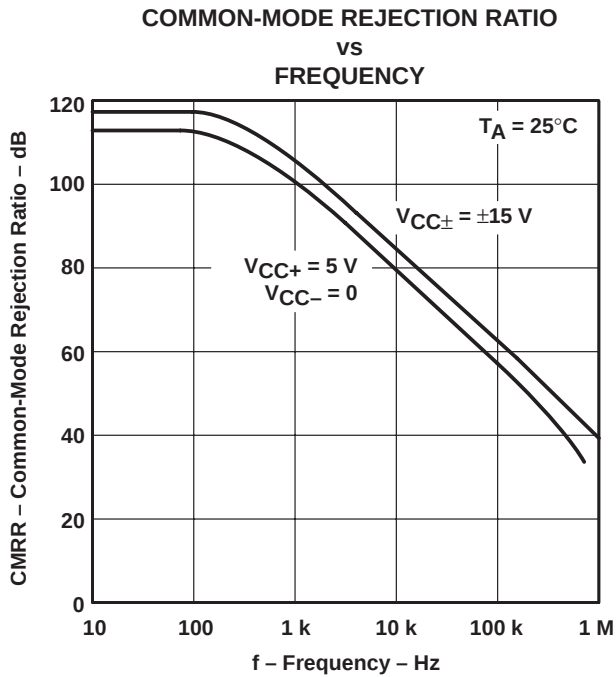


Figure 13

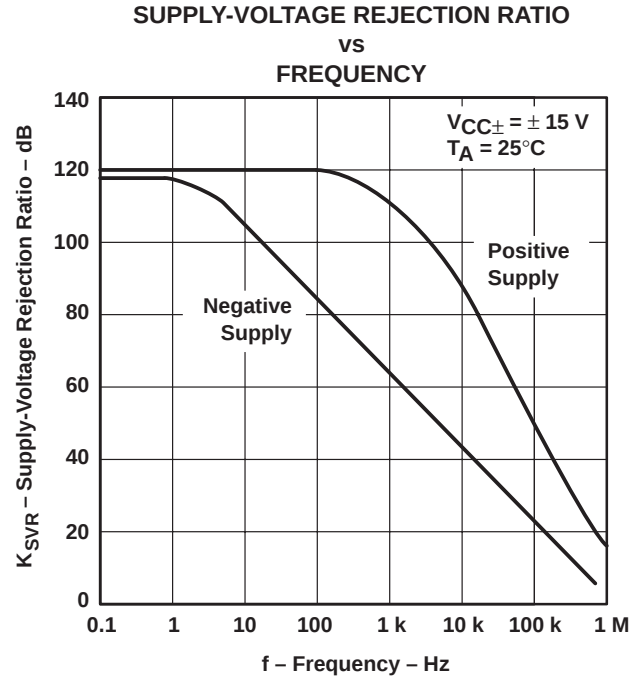


Figure 14

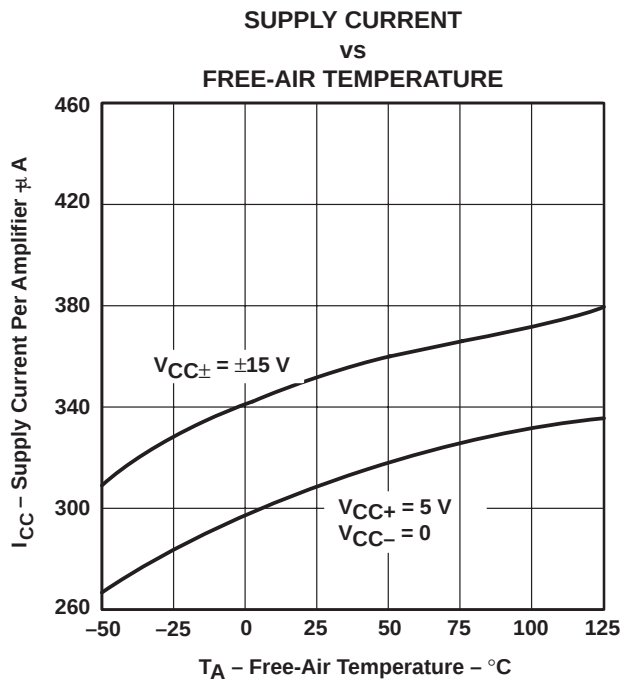


Figure 15

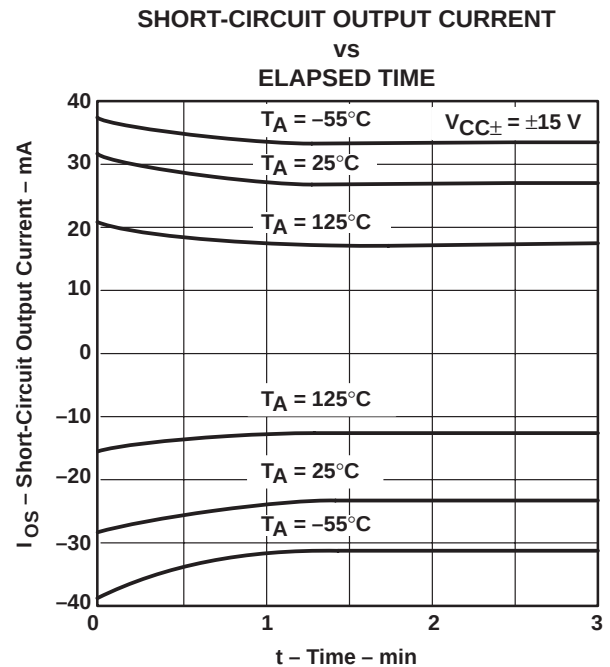


Figure 16

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

LT1014, LT1014A, LT1014D
QUAD PRECISION OPERATIONAL AMPLIFIERS

SLOS039C – JULY 1989 – REVISED SEPTEMBER 1999

TYPICAL CHARACTERISTICS

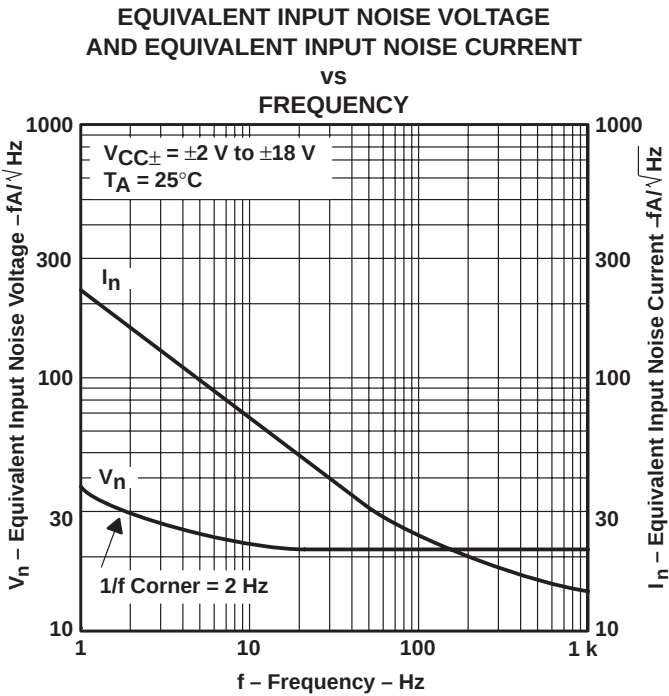


Figure 17

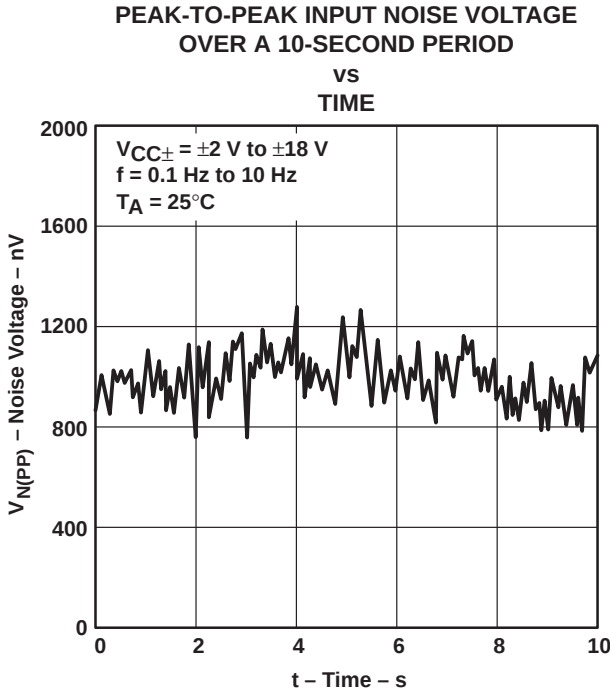


Figure 18

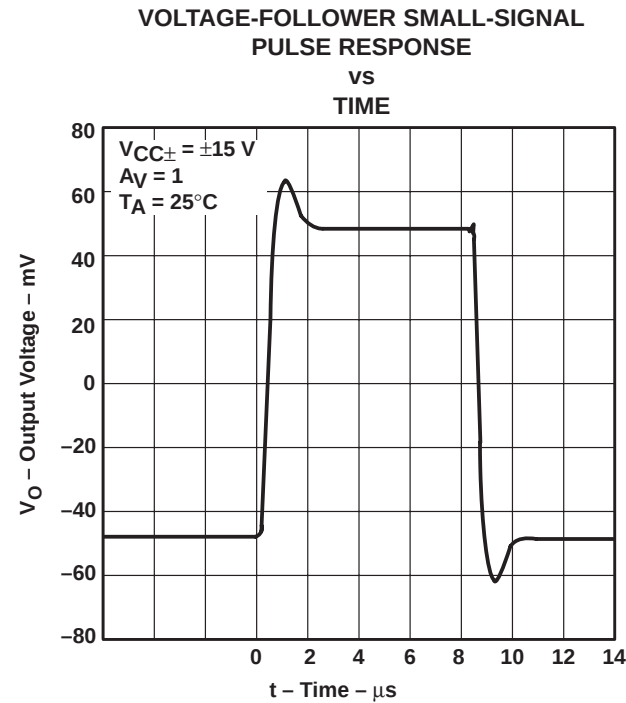


Figure 19

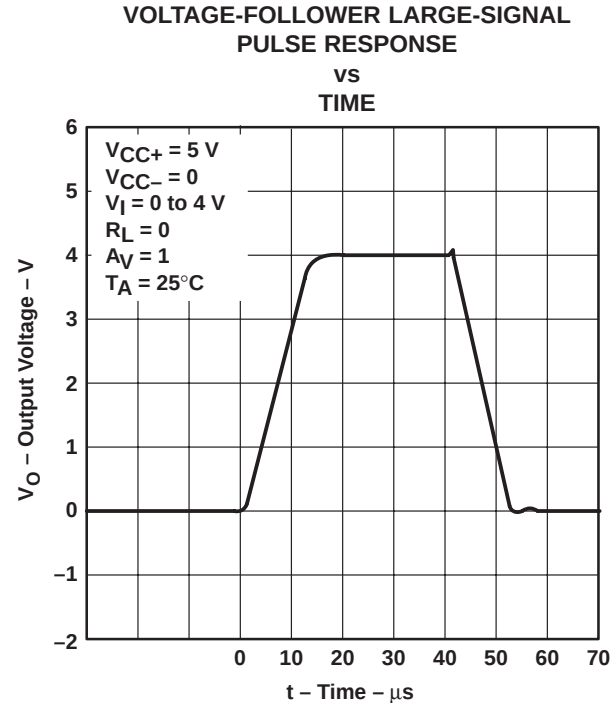


Figure 20

TYPICAL CHARACTERISTICS

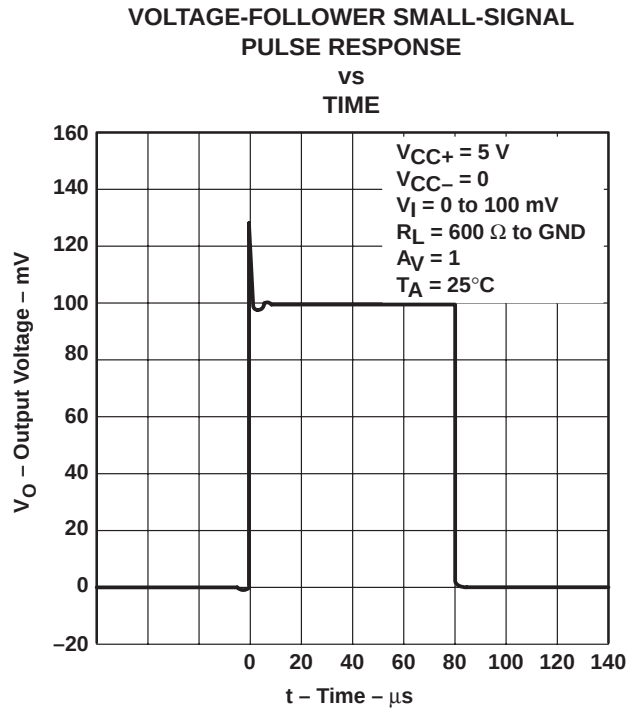


Figure 21

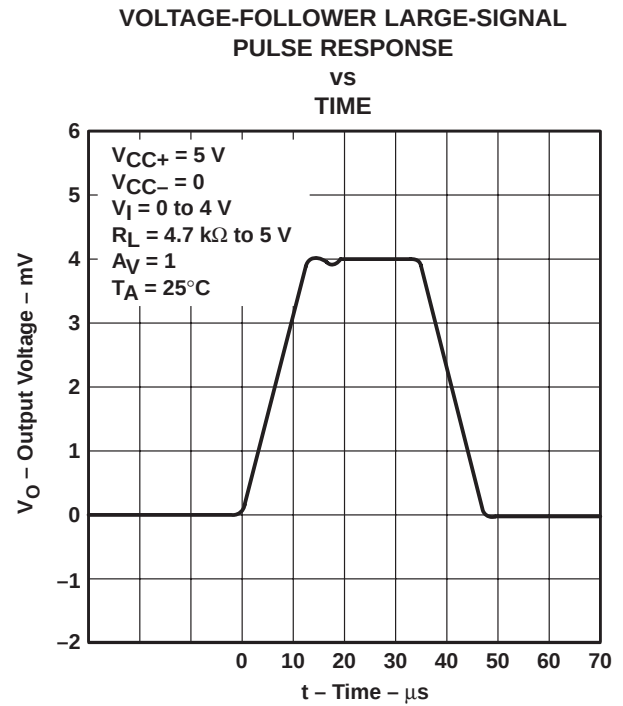


Figure 22

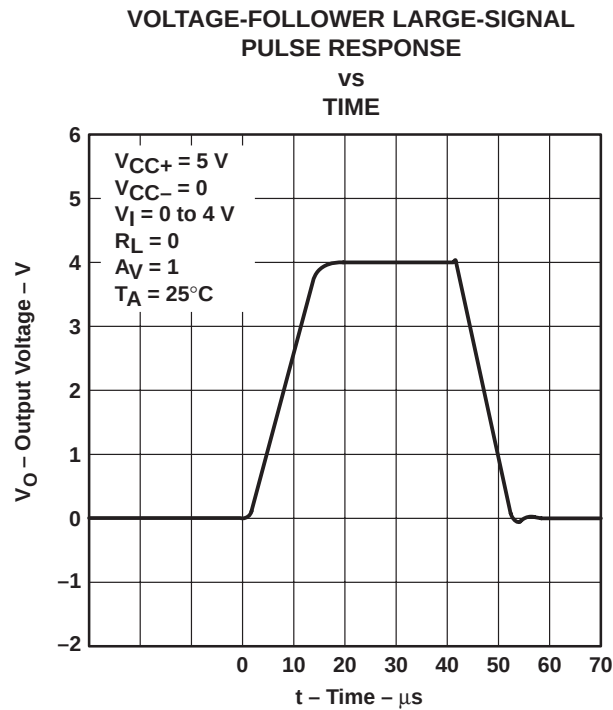


Figure 23

LT1014, LT1014A, LT1014D

QUAD PRECISION OPERATIONAL AMPLIFIERS

SLOS039C – JULY 1989 – REVISED SEPTEMBER 1999

APPLICATION INFORMATION

single-supply operation

The LT1014 is fully specified for single-supply operation ($V_{CC-} = 0$). The common-mode input voltage range includes ground, and the output swings within a few millivolts of ground.

Furthermore, the LT1014 has specific circuitry that addresses the difficulties of single-supply operation, both at the input and at the output. At the input, the driving signal can fall below 0 V, either inadvertently or on a transient basis. If the input is more than a few hundred millivolts below ground, the LT1014 is designed to deal with the following two problems that can occur:

1. On many other operational amplifiers, when the input is more than a diode drop below ground, unlimited current flows from the substrate (V_{CC-} terminal) to the input, which can destroy the unit. On the LT1014, the 400- Ω resistors in series with the input (see schematic) protect the device even when the input is 5 V below ground.
2. When the input is more than 400 mV below ground (at $T_A = 25^\circ\text{C}$), the input stage of similar type operational amplifiers saturates, and phase reversal occurs at the output. This can cause lockup in servo systems. Because of unique phase-reversal protection circuitry (Q21, Q22, Q27, and Q28), the LT1014 outputs do not reverse, even when the inputs are at -1.5 V (see Figure 24).

However, this phase-reversal protection circuitry does not function when the other operational amplifier on the LT1014 is driven hard into negative saturation at the output. Phase-reversal protection does not work on an amplifier:

- When 4's output is in negative saturation (the outputs of 2 and 3 have no effect)
- When 3's output is in negative saturation (the outputs of 1 and 4 have no effect)
- When 2's output is in negative saturation (the outputs of 1 and 4 have no effect)
- When 1's output is in negative saturation (the outputs of 2 and 3 have no effect)

At the output, other single-supply designs either cannot swing to within 600 mV of ground or cannot sink more than a few microamperes while swinging to ground. The all-npn output stage of the LT1014 maintains its low output resistance and high gain characteristics until the output is saturated. In dual-supply operations, the output stage is free of crossover distortion.

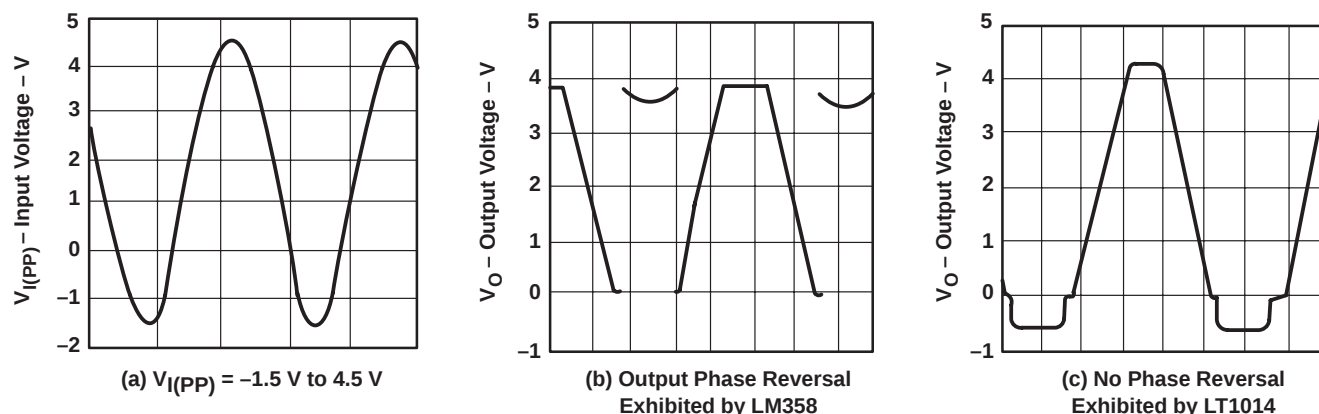


Figure 24. Voltage-Follower Response
With Input Exceeding the Negative Common-Mode Input Voltage Range

APPLICATION INFORMATION

comparator applications

The single-supply operation of the LT1014 can be used as a precision comparator with TTL-compatible output. In systems using both operational amplifiers and comparators, the LT1014 can perform multiple duties (see Figures 25 and 26).

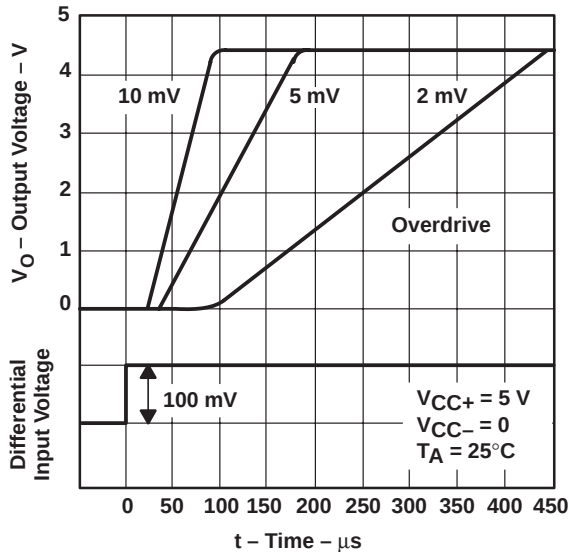


Figure 25. Low-to-High-Level Output Response for Various Input Overdrives

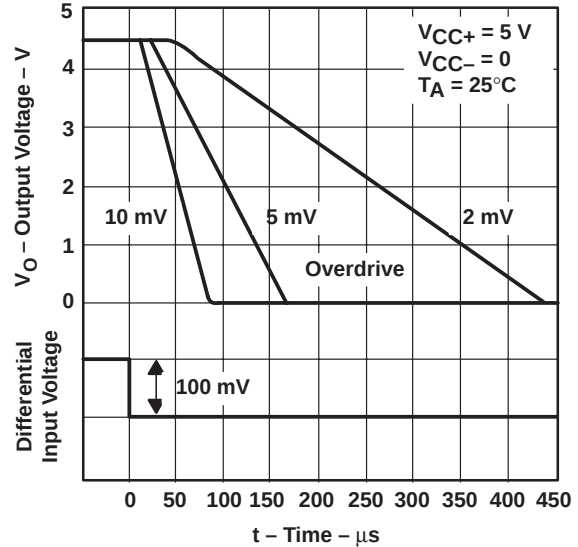


Figure 26. High-to-Low-Level Output Response for Various Input Overdrives

low-supply operation

The minimum supply voltage for proper operation of the LT1014 is 3.4 V (three Ni-Cad batteries). Typical supply current at this voltage is 290 μ A; therefore, power dissipation is only 1 mW per amplifier.

offset voltage and noise testing

Figure 30 shows the test circuit for measuring input offset voltage and its temperature coefficient. This circuit with supply voltages increased to ± 20 V is also used as the burn-in configuration.

The peak-to-peak equivalent input noise voltage of the LT1014 is measured using the test circuit shown in Figure 27. The frequency response of the noise tester indicates that the 0.1-Hz corner is defined by only one zero. The test time to measure 0.1-Hz to 10-Hz noise should not exceed 10 seconds, as this time limit acts as an additional zero to eliminate noise contribution from the frequency band below 0.1 Hz.

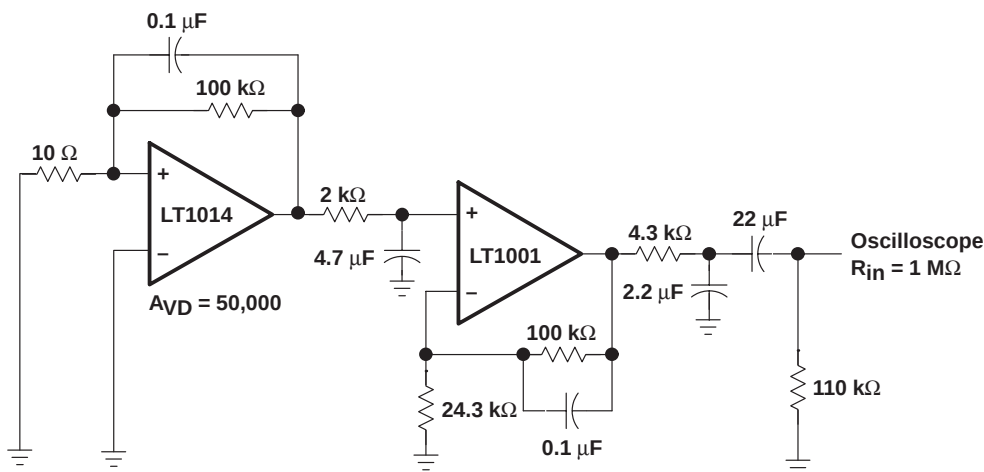
An input noise-voltage test is recommended when measuring the noise of a large number of units. A 10-Hz input noise-voltage measurement correlates well with a 0.1-Hz peak-to-peak noise reading because both results are determined by the white noise and the location of the $1/f$ corner frequency.

Noise current is measured by the circuit and formula shown in Figure 28. The noise of the source resistors is subtracted.

LT1014, LT1014A, LT1014D QUAD PRECISION OPERATIONAL AMPLIFIERS

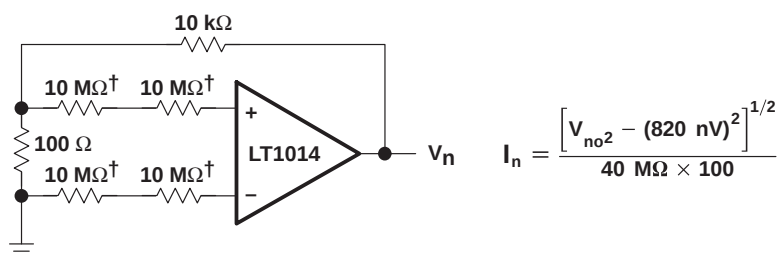
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APPLICATION INFORMATION



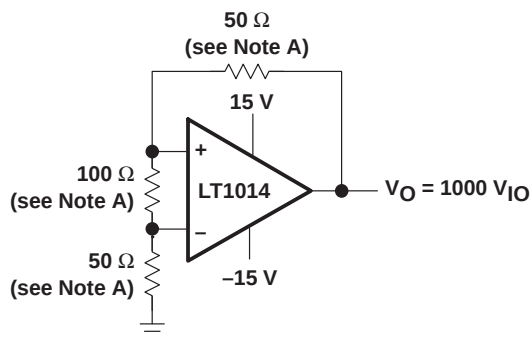
NOTE A: All capacitor values are for nonpolarized capacitors only.

Figure 27. 0.1-Hz to 10-Hz Peak-to-Peak Noise Test Circuit



† Metal-film resistor

Figure 28. Noise-Current Test Circuit and Formula



NOTE A: Resistors must have low thermoelectric potential.

Figure 29. Test Circuit for V_{IO} and αV_{IO}

APPLICATION INFORMATION

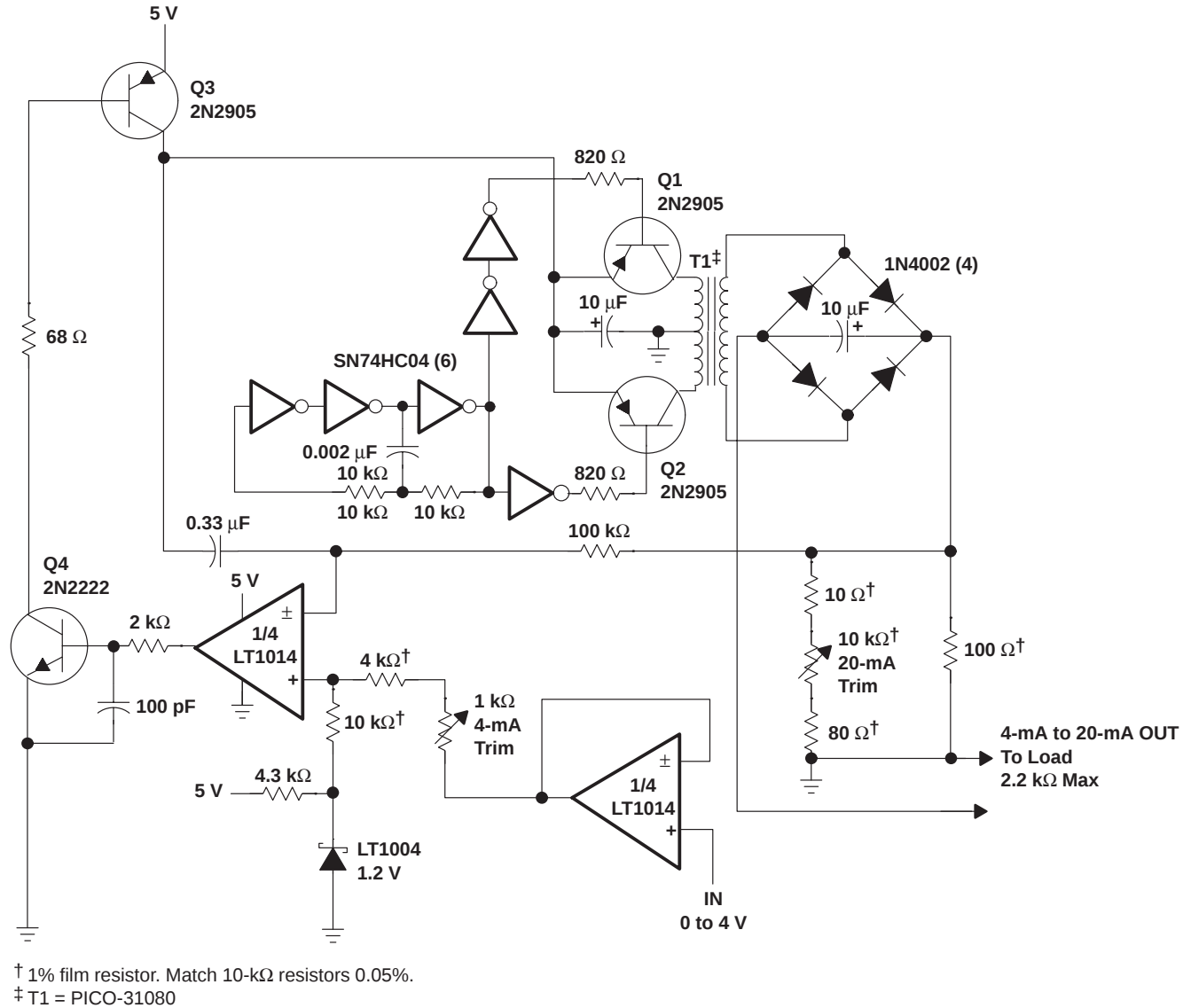


Figure 30. 5-V Powered, 4-mA to 20-mA Current-Loop Transmitter With 12-Bit Accuracy

LT1014, LT1014A, LT1014D QUAD PRECISION OPERATIONAL AMPLIFIERS

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APPLICATION INFORMATION

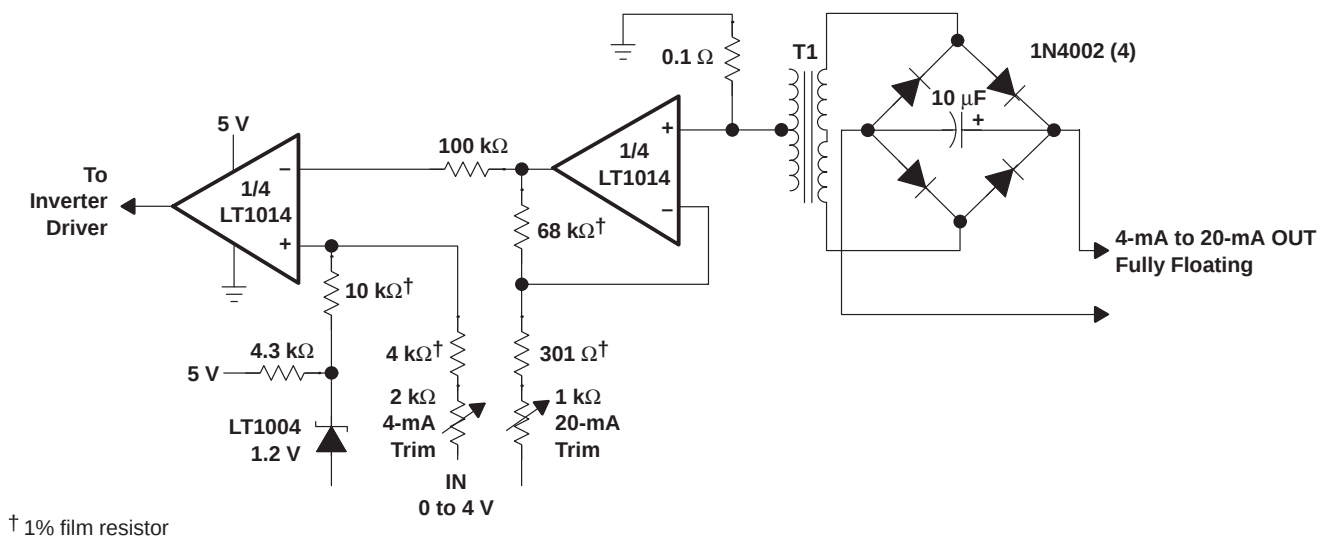
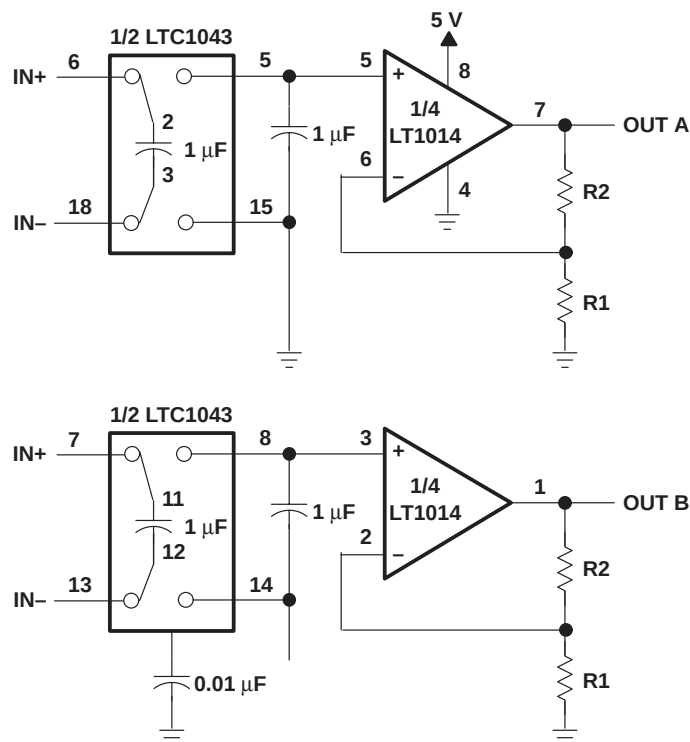


Figure 31. Fully Floating Modification to 4-mA to 20-mA Current-Loop Transmitter With 8-Bit Accuracy



NOTE A: $V_{IO} = 150 \mu V$, $A_{VD} = (R1/R2) + 1$, $CMRR = 120 \text{ dB}$, $V_{ICR} = 0 \text{ to } 5 \text{ V}$

Figure 32. 5-V Single-Supply Dual Instrumentation Amplifier

The circuit diagram shows a differential amplifier using three LT1014 operational amplifiers. The first stage consists of two op-amp buffers (LT1014) configured as a differential pair. The inputs are IN+ and IN-, each followed by a 20 kΩ resistor. The non-inverting inputs (pins 5 and 6) are connected to the input signals. The inverting inputs (pins 3 and 2) are connected to the outputs of the first stage (pins 1 and 7) via 200 kΩ resistors. A 1 μF capacitor is connected between the two input lines. A 5 V diode is connected between the two input lines. A 2 kΩ resistor (RG) is connected between the two input lines. The second stage consists of two op-amp buffers (LT1014) configured as a differential pair. The non-inverting inputs (pins 12 and 13) are connected to the outputs of the first stage (pins 1 and 7) via 10 kΩ resistors. The inverting inputs (pins 9 and 8) are connected to the outputs of the second stage (pins 14 and 15) via 10 kΩ resistors. A 5 V diode is connected between the two input lines. A 2 kΩ resistor (RG) is connected between the two input lines. The output of the second stage is OUT. A 5 V diode is connected between the two input lines. A 2 kΩ resistor (RG) is connected between the two input lines. The third stage consists of a single op-amp buffer (LT1014) configured as a differential pair. The non-inverting input (pin 10) is connected to the output of the second stage (pin 14) via a 10 kΩ resistor. The inverting input (pin 9) is connected to the output of the second stage (pin 15) via a 10 kΩ resistor. The output of the third stage (pin 8) is connected to the input of the cable shields.

NOTE A: $A_{VP} = (400,000/RG) + 1$



PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
5962-89677012A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type
5962-8967701CA	ACTIVE	CDIP	J	14	1	TBD	A42 SNPB	N / A for Pkg Type
5962-89677022A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type
5962-8967702CA	ACTIVE	CDIP	J	14	1	TBD	A42 SNPB	N / A for Pkg Type
LT1014AMFKB	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type
LT1014AMJ	ACTIVE	CDIP	J	14	1	TBD	A42 SNPB	N / A for Pkg Type
LT1014AMJB	ACTIVE	CDIP	J	14	1	TBD	A42 SNPB	N / A for Pkg Type
LT1014CN	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
LT1014CNE4	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
LT1014DDW	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
LT1014DDWE4	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
LT1014DDWG4	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
LT1014DDWR	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
LT1014DDWRE4	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
LT1014DDWRG4	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
LT1014DIDW	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
LT1014DIDWG4	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
LT1014DIDWR	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
LT1014DIDWRG4	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
LT1014DIN	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
LT1014DINE4	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
LT1014DMDW	ACTIVE	SOIC	DW	16	40	TBD	CU NIPDAU	Level-1-220C-UNLIM
LT1014DMDWG4	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
LT1014DN	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
LT1014DNE4	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
LT1014IN	OBSOLETE	PDIP	N	14		TBD	Call TI	Call TI
LT1014MFKB	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type
LT1014MJ	ACTIVE	CDIP	J	14	1	TBD	A42 SNPB	N / A for Pkg Type
LT1014MJB	ACTIVE	CDIP	J	14	1	TBD	A42 SNPB	N / A for Pkg Type

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBsolete: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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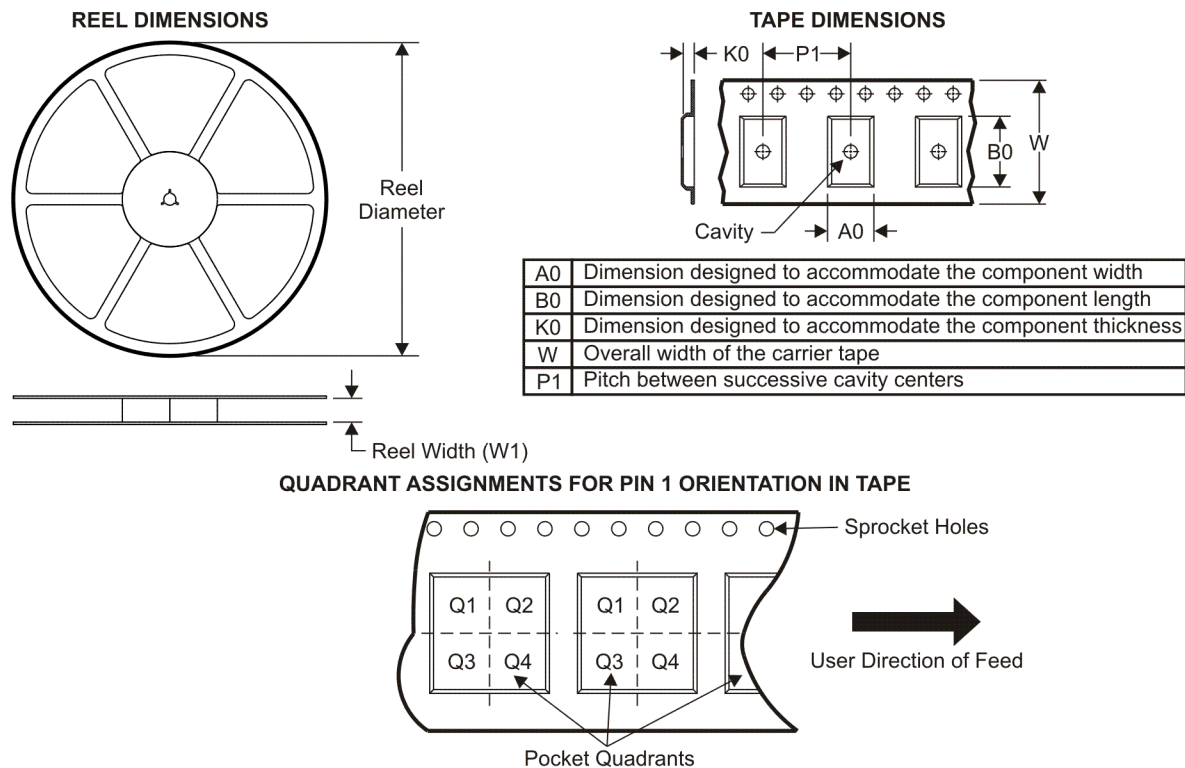
OTHER QUALIFIED VERSIONS OF LT1014D :

- Enhanced Product: [LT1014D-EP](#)

NOTE: Qualified Version Definitions:

- Enhanced Product - Supports Defense, Aerospace and Medical Applications

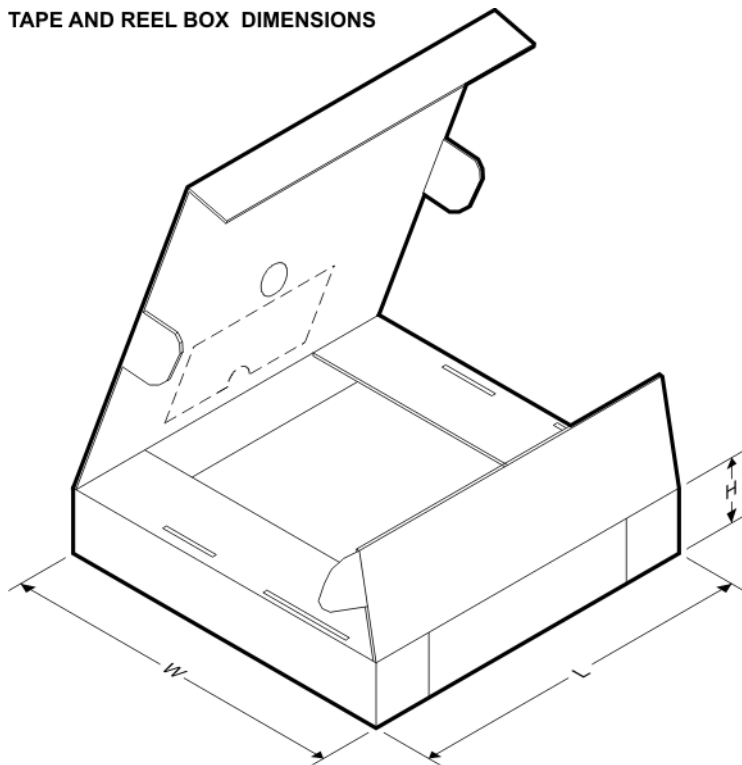
TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LT1014DDWR	SOIC	DW	16	2000	330.0	16.4	10.75	10.7	2.7	12.0	16.0	Q1
LT1014DIDWR	SOIC	DW	16	2000	330.0	16.4	10.75	10.7	2.7	12.0	16.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LT1014DDWR	SOIC	DW	16	2000	346.0	346.0	33.0
LT1014DIDWR	SOIC	DW	16	2000	346.0	346.0	33.0

J (R-GDIP-T**)

14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE



PINS ** DIM	14	16	18	20
A	0.300 (7,62) BSC	0.300 (7,62) BSC	0.300 (7,62) BSC	0.300 (7,62) BSC
B MAX	0.785 (19,94)	.840 (21,34)	0.960 (24,38)	1.060 (26,92)
B MIN	—	—	—	—
C MAX	0.300 (7,62)	0.300 (7,62)	0.310 (7,87)	0.300 (7,62)
C MIN	0.245 (6,22)	0.245 (6,22)	0.220 (5,59)	0.245 (6,22)



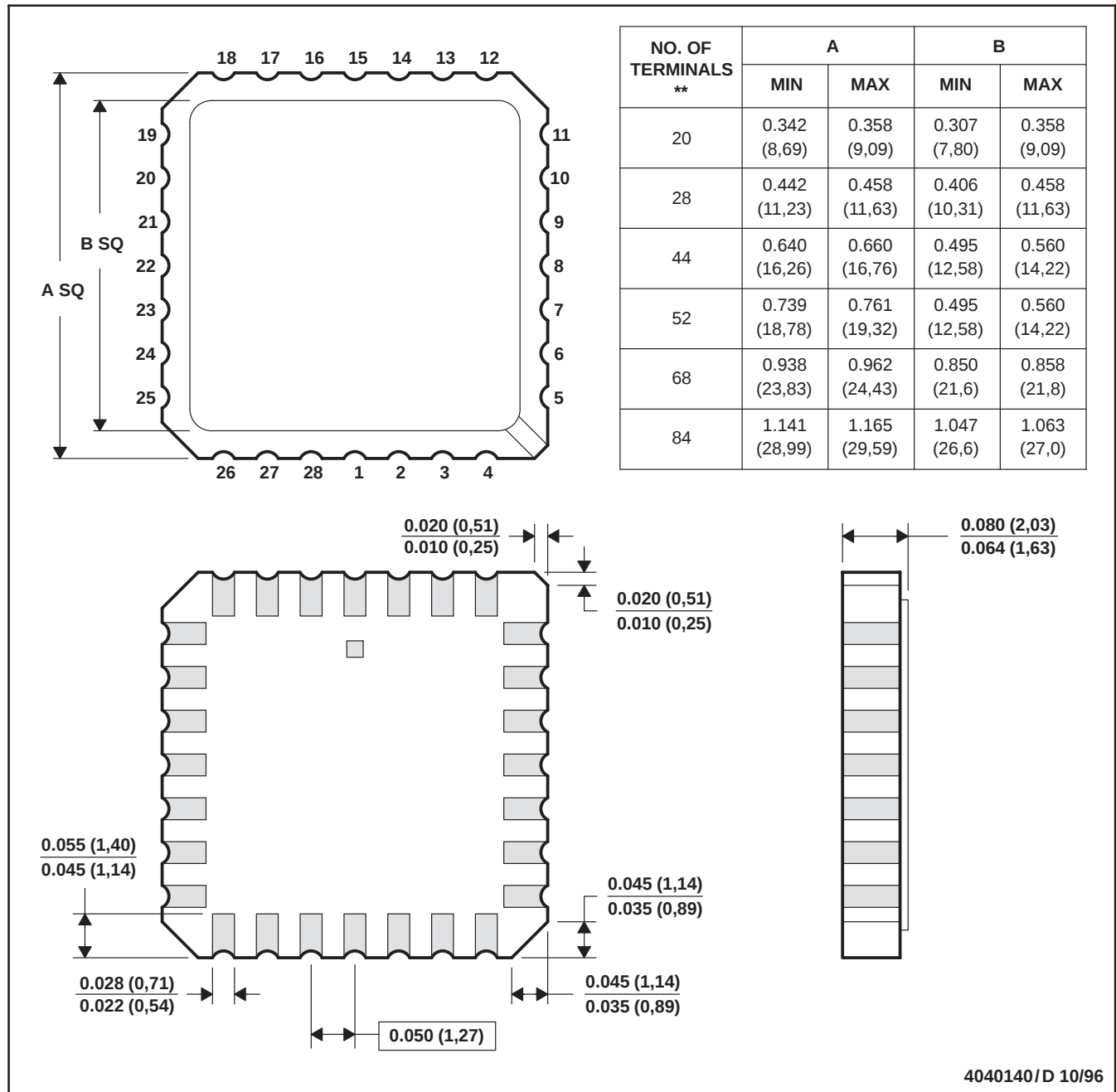
4040083/F 03/03

- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. This package is hermetically sealed with a ceramic lid using glass frit.
 - D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
 - E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

FK (S-CQCC-N**)

LEADLESS CERAMIC CHIP CARRIER

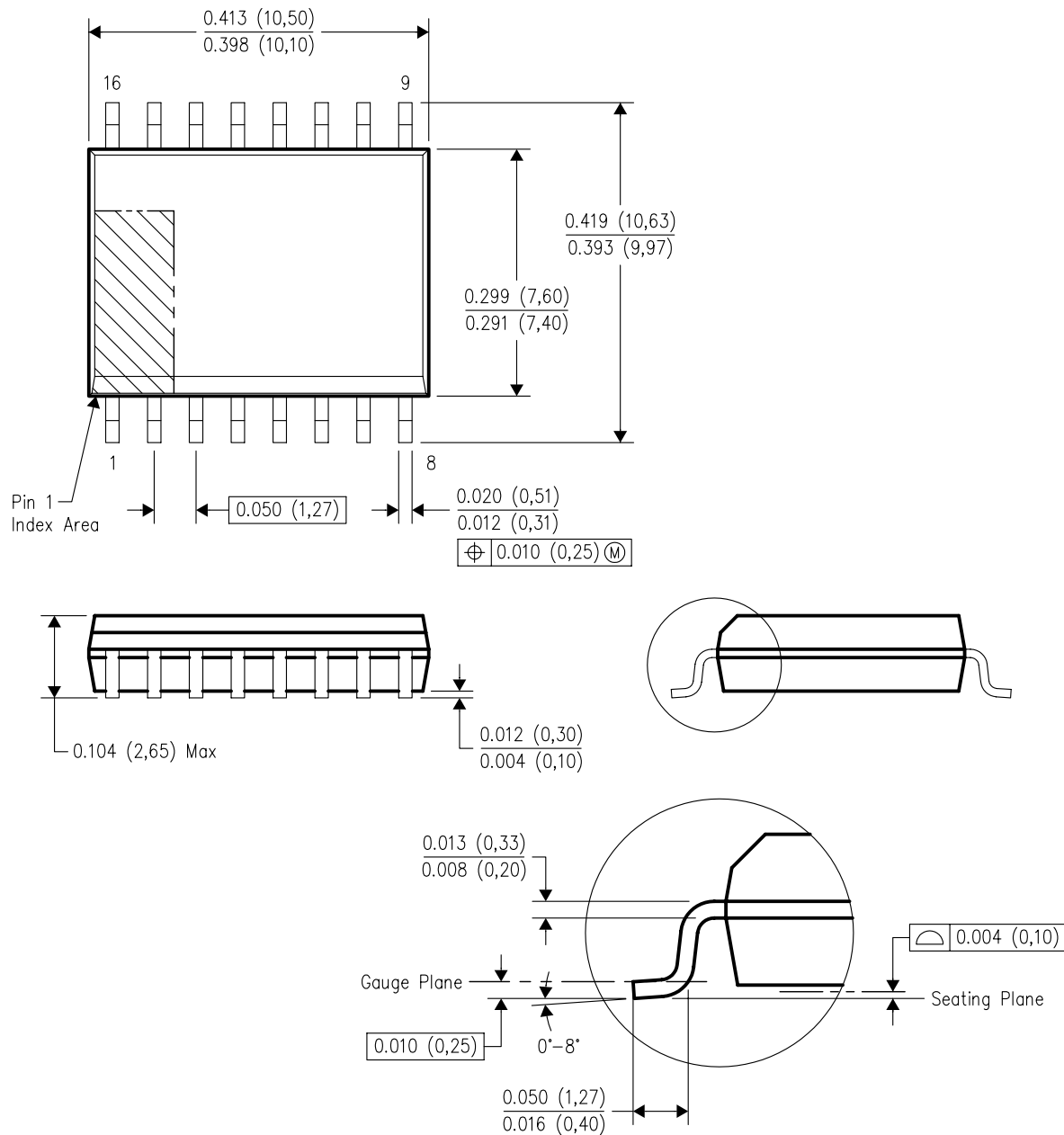
28 TERMINAL SHOWN



- NOTES:
- All linear dimensions are in inches (millimeters).
 - This drawing is subject to change without notice.
 - This package can be hermetically sealed with a metal lid.
 - The terminals are gold plated.
 - Falls within JEDEC MS-004

DW (R-PDSO-G16)

PLASTIC SMALL-OUTLINE PACKAGE



4040000-2/F 06/2004

N (R-PDIP-T**)

16 PINS SHOWN

PLASTIC DUAL-IN-LINE PACKAGE



PINS ** DIM	14	16	18	20
A MAX	0.775 (19,69)	0.775 (19,69)	0.920 (23,37)	1.060 (26,92)
A MIN	0.745 (18,92)	0.745 (18,92)	0.850 (21,59)	0.940 (23,88)
MS-001 VARIATION	AA	BB	AC	AD



4040049/E 12/2002

NOTES:

- A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
-  Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
 The 20 pin end lead shoulder width is a vendor option, either half or full width.

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